Manipulating all-pH hydrogen evolution kinetics on metal sulfides through one-pot simultaneously derived multi-interface engineering and phosphorus doping

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Figure S2 XRD of reference sample NiS/Ni₃S₄.



Figure S3 SEM images of reference sample NiS/Ni₃S₄.



Figure S4 SEM images of $NiS/WS_2/Ni_3S_4$ prepared with 1g PW₁₂.



Figure S5 Linear sweep voltammetry (LSV) curve and Tafel plot in neutral condition.



Figure S6 Non-Faradaic scan for double-layer capacitance in alkaline HER, and EIS Nyquist plots.



Figure S7 Non-Faradaic scan for double-layer capacitance in alkaline HER, and EIS Nyquist plots.



Figure S8 Time-dependent current density curve in neutral condition.



Figure S9 SEM images of NiS/WS $_2$ /Ni $_3$ S $_4$ after alkaline HER test.



Figure S10 XRD pattern of NiS/WS₂/Ni₃S₄ after alkaline HER test.



Figure 11 TEM image of of $NiS/WS_2/Ni_3S_4$ after alkaline HER test.